EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|----------|-------------------|---|---|---------------------|---------|------------------|
| L10 | 6 | 8 and 9 | US-PGPUB; USPAT; USOCR | OR | ON | 2007/09/01 13:49 |
| L9 | 11 | ((barium adj strontium adj titanate) bst) with oxygen with (profile contour concentration grade graded grading) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/09/01 13:49 |
| L1 | 11 | bst with oxygen with (profile contour concentration grade graded grading) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/09/01 13:49 |
| L8 | 7929 [`] | ((438/240) or (438/287) or (438/761) or (438/763) or (438/785) or (257/310) or (257/635) or (257/637) or (257/638) or (257/e21.625) or (257/e21.639) or (257/e21.01)).CCLS. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/09/01 13:48 |
| L7 | 0 | bst with oxygen with (profile contour concentration grade graded grading) | FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/09/01 13:47 |
| L2 | 4 | ("5728603" "5853500").PN. OR ("6159868").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/09/01 12:14 |
| S14 1 | 133 | S140 and semiconductor | US-PGPUB; USPAT; USOCR | OR | ON | 2007/09/01 12:02 |
| S14 0 | 184 | S139 and (substrate wafer) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:08 |
| S13 9 | 225 | S136 and @ad<="20000607" | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:07 |
| S13 8 | 279 | S135 and (first second) with ((molar adj ratio) concentration) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:07 |
| S13 2 | 359 | S131 and @ad<="20000607" | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:07 |
| S13 7 | 590 | S136 and (substrate wafer) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:06 |
| S13 6 | 681 | S135 and ((molar with ratio) concentration) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:06 |
| S13 5 | 1697 | (stack multiple first second third) with (bst (barium adj strontium adj titanate)) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 15:05 |

EAST Search History

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|----------|-------|--|------------------------------|----|-----|------------------|
| S13 4 | 14 | ("3972059" "5789268" "5807774" "6010744" "6025257" "6078072"). PN. OR ("6403441").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/08/31 15:04 |
| S13 3 | 251 | S132 and ("438" "257").clas. | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:57 |
| S11 7 | 16 | S116 and @ad<="20000607" | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:57 |
| S13 1 | 1615 | S130 and (substrate wafer) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:56 |
| S12 8 | 60 | S127 and (substrate wafer) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:56 |
| S13 0 | 1799 | S120 and (barium ba strontium st) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:55 |
| S12 0 | 3757 | S119 and S114 | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:55 |
| S12 9 | 28 | ("20020005556" "20020043666" "20020106536" "20020130340" "20020145168" "20020153579" "5434109" "5688724" "6013553" "6020024" "6020243" "6114258" "6163049" "6168958" "6184155" "6210999" "6251761" "6258675" "6265268" "6291866" "6291867" "6297107" "6309927" "6319730" "6319775" "6444592").PN. OR ("6790755").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/08/31 13:43 |
| S12 7 | 73 | ((tantalum adj (oxide pentoxide)) tao "ta.sub.2o.sub.5" "ta.sub.xo.sub.y") with (oxygen with (implant\$5 dop\$4)) | US-PGPÚB; USPAT; USOCR | OR | ON | 2007/08/31 13:34 |
| S11 3 | 41714 | (tantalum adj (oxide pentoxide)) tao "ta.sub.2o.sub.5" "ta.sub.xo.sub.y" | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 13:34 |
| S12 6 | 1 | ("5910880").PN. | USPAT; USOCR | OR | OFF | 2007/08/31 13:33 |
| S12 5 | 119 | ("3668004" "3730766" "3967310" "4335391" "4495219" "4636833" "4659606" "4690846" "4891684" "4937650" "4989056" "5072269" "5091761" "5111355" "5173835" "5225286").PN. OR ("5688724").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/08/31 12:33 |
| S12 4 | 35 | S123 and @ad<="20000607" | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:35 |

EAST Search History

| S12 3 | 137 | S122 and semiconductor | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:34 |
|----------|--------|---|------------------------------|----|----|------------------|
| S12 2 | 141 | S121 and (substrate wafer) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:34 |
| S12 1 | 143 | S119 with S114 | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:34 |
| S11 9 | 43819 | "high-k" (high adj (dielectric insulating)) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:34 |
| S11 8 | 111 | S116 not S117 | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 11:33 |
| S11 6 | 127 | S115 and semiconductor | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 10:54 |
| S11 5 | 175 | S113 with S114 | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 10:54 |
| S11 4 | 159145 | oxygen with (concentration profile gradient amount ratio) | US-PGPUB; USPAT; USOCR | OR | ON | 2007/08/31 10:54 |